NSN 5961-01-117-5660

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-117-5660 **Inclosure Material:** Metal **Overall Length:** 0.210 inches Overall Diameter: 0.285 inches **End Application:** An/apx-76b 80249 fscm **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80249-911376 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 flange and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**